

1A up to 40V Input Step-Down DC/DC Regulator ME3116

General Description

The ME3116 is PWM DC/DC buck (step-down) regulators. With a wide input range from 4.75V-40V, they are suitable for a wide range of applications such as power conditioning from unregulated sources. They feature a low $R_{DS(on)}$ (0.9 Ω typical) internal switch for maximum efficiency 90%. Operating frequency is fixed at 550 KHz allowing the use of small external components while still being able to have low output voltage ripple. The system has PWM and PFM switching function to ensure high efficiency under low load. The built-in soft-start prevents inrush current at turn-on. the ME3116 is optimized for up to 1A load current. Both have a 0.8V nominal feedback voltage. Additional features include: thermal shutdown, VIN under-voltage lockout, and gate drive under-voltage lockout.

Selection Guide

ME 3116 X XXX

Environment mark
Package:
 e.g.: M6: SOT23-6
Version or Function
 e.g.:
 A: First version
Product Type
Product Series

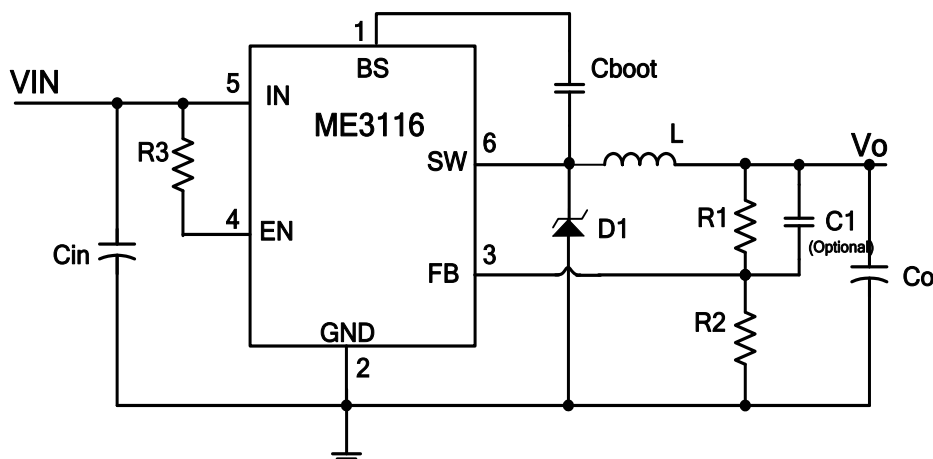
Features

- Feedback pin voltage of 0.8V
- Input voltage range of 4.75V to 40V
- Output current up to 1A
- 550 KHz switching frequency
- maximum efficiency 90%
- PWM and PFM switching
- Low shutdown I_Q , 10 μ A typical
- Short circuit protected
- Internally compensated
- Soft-start circuitry
- SOT23-6 package

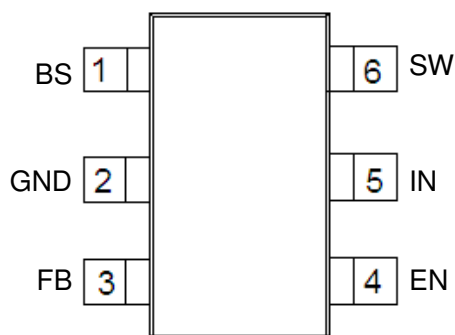
Applications

- Battery powered equipment
- Industrial distributed power applications
- Portable media players
- Portable hand held instruments

Typical Application Circuit



Pin Configuration



Pin Assignment

Pin Num.	Symbol	Function
1	BS	SW FET gate bias voltage. Connect C_{BOOT} cap between BS and SW.
2	GND	Ground
3	FB	Feedback pin: Set feedback voltage divider ratio with $V_{OUT} = V_{FB} (1 + (R1/R2))$. Resistors should be in the 100-10K Ω range to avoid input bias errors.
4	EN	Logic level shutdown input. Pull to GND to disable the device and pull high to enable the device. If this function is not used tie to VIN with a resistor 1M Ω .
5	IN	Power input voltage pin: 4.75V to 40V normal operating range
6	SW	Power FET output: Connect to inductor, diode, and C_{BOOT} cap.

Absolute Maximum Ratings

Parameter	Rating	Unit
Power supply voltage, VIN	-0.3~45	V
EN voltage V_{EN}	6	V
SW Voltage V_{SW}	-0.3~45	V
Feedback voltage V_{FB}	-0.3~5	V
Switch voltage V_{SW}	-1V to 45	V
BS Voltage above SW Voltage	7	V
Maximum Junction Temperature	150	°C
Lead Temperature	300	°C
ESD Susceptibility: Human Body Model	2	KV

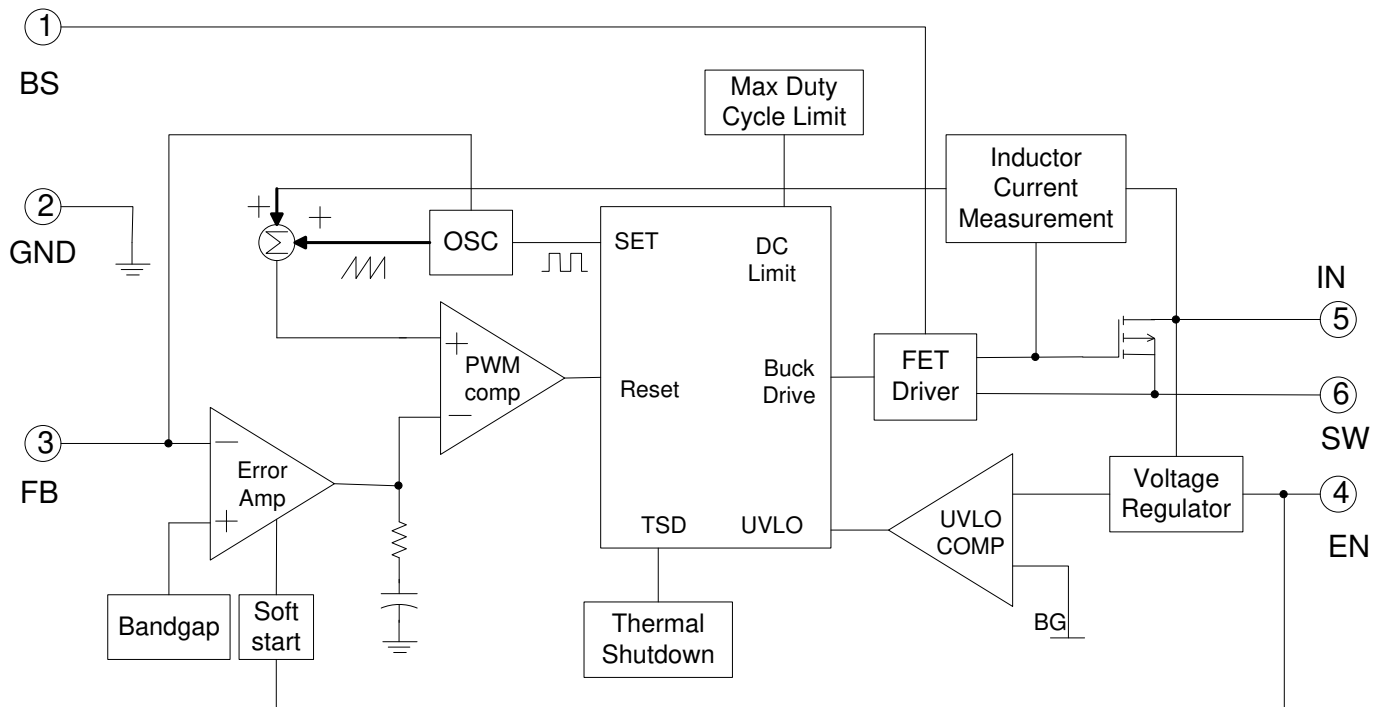
Caution: The absolute maximum ratings are rated values exceeding which the product could suffer physical damage.

These values must therefore not be exceeded under any conditions.

Recommended working condition

Parameter	Min	Max	Unit
Power supply voltage, VIN	4.75	40	V
SW voltage	-	42	V
Operating Junction Temperature Range	-40	125	°C
Storage Temperature	-65	150	°C

Block Diagram



Electrical Characteristics

Specifications in standard type face are for $T_J = 25^{\circ}\text{C}$ and those with boldface type apply over the full Operating Temperature Range ($T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$). Minimum and Maximum limits are guaranteed through test, design, or statistical correlation. Typical values represent the most likely parametric norm at $T_J = +25^{\circ}\text{C}$, and are provided for reference purposes only. Unless otherwise stated the following conditions apply: $V_{IN} = 12\text{V}$.

Item	Symbol	Test condition	Min	Typ.	Max	Unit
Quiescent current	I_Q	EN=0 V	-	0.7	2	μA
		Device On, Not Switching	-	1.3	1.75	mA
		Device On, No Load	-	1.35	1.85	
Switch ON resistance	$R_{DS(on)}$		-	0.9	1.6	Ω
Switch leakage current	I_{LSW}	$V_{IN} = 40\text{V}$	-	0	0.5	μA
Switch Current Limit	I_{CL}		-	1.2	-	A
Feedback pin Bias Current	I_{FB}		-	0.1	1	μA
Feedback voltage	V_{FB}		0.788	0.8	0.812	V
Minimum ON time	t_{MIN}		-	100	-	nS
Switching Frequency	f_{SW}	$V_{FB} = 0.5\text{V}$	-	550	-	KHz
Short Circuit Frequency	F_{short}	$V_{FB} = 0\text{V}$	-	140	-	KHz
Maximum Duty Cycle	D_{MAX}	$V_{FB} = 1.0\text{V}$	-	88	94	%
VIN UVLO Threshold	V_{uvp}	On threshold	4.4	3.9	-	V
	V_{uvhy}	Off threshold	-	3.7	3.5	V
EN Shutdown Threshold	V_{EN_ST}	V_{EN} Rising	4	2	-	V
Thermal Shutdown	T		-	160	-	$^{\circ}\text{C}$

Application Information

The ME3116 has dedicated protection circuitry running during normal operation to protect the IC. The thermal shutdown circuitry turns off the power device when the die temperature reaches excessive levels. The UVLO comparator protects the power device during supply power startup and shutdown to prevent operation at voltages less than the minimum input voltage. A gate drive (BS) under-voltage lockout is included to guarantee that there is enough gate drive voltage to drive the MOSFET before the device tries to start switching. The ME3116 also features a shutdown mode decreasing the supply current to approximately 0.7μA.

Continuous Conduction Mode

The ME3116 contains a current-mode, PWM buck regulator. A buck regulator steps the input voltage down to a lower output voltage. In continuous conduction mode (when the inductor current never reaches zero at steady state), the buck regulator operates in two cycles. The power switch is connected between VIN and SW. In the first cycle of operation the transistor is closed and the diode is reverse biased. Energy is collected in the inductor and the load current is supplied by Co and the rising current through the inductor. During the second cycle the transistor is open and the diode is forward biased due to the fact that the inductor current cannot instantaneously change direction. The energy stored in the inductor is transferred to the load and output capacitor. The ratio of these two cycles determines the output voltage. The output voltage is defined approximately as: $D=V_o/V_{IN}$ and $D' = (1- D)$ where D is the duty cycle of the switch. D and D' will be required for design calculations.

Design Procedure

This section presents guidelines for selecting external components.

Setting the Output Voltage

The output voltage is set using the feedback pin and a resistor divider connected to the output as shown on the front page schematic. The feedback pin voltage is 0.8V, so the ratio of the feedback resistors sets the output voltage

according to the following equation: $V_o = 0.8 * \frac{R1+R2}{R2}$

Typically R2 will be given as 100Ω-10 KΩ for a starting value. To solve for R1 given R2 and Vo use :

$$R1 = R2 * (\frac{V_o}{0.8V} - 1)$$

Feedforward Capacitor Selection

Internal compensation function allows users saving time in design and saving cost by reducing the number of external components. The use of a feedforward capacitor C1 in the feedback network is recommended to improve the transient response or higher phase margin.

For optimizing the feedforward capacitor, knowing the cross frequency is the first thing. The cross frequency (or the converter bandwidth) can be determined by using a network analyzer. When getting the cross frequency with no feedforward capacitor identified, the value of feedforward capacitor C1 can be calculated with the following equation:

$$C1 = \frac{1}{2\pi * F_{CROSS}} * \sqrt{\frac{1}{R1} * (\frac{1}{R1} + \frac{1}{R2})}$$

Where F_{CROSS} is the cross frequency. to reduce transient ripple, the feedforward capacitor value can be increased to push the cross frequency to higher region. Although this can improve transient response, it also decreases phase margin and causes more ringing. In the other hand, if more phase margin is desired, the feedforward capacitor value can be decreased to push the cross frequency to lower region. In general, the feedforward capacitor range is between 10pF to 220pF.

FB Compensation capacitor selection recommendation				Note
	R1	R2	C1	VIN≤40V
VO=5V	5.1KΩ	1KΩ	47p-220p	
	56KΩ	10KΩ	47p-100p	
	112KΩ	20KΩ	20p	
VO=3.3V	3.3KΩ	1KΩ	440p-660p	VIN≤24V
	10KΩ	3KΩ	100p-330p	
	33KΩ	10KΩ	67p-100p	
	100KΩ	30KΩ	20p	

Input Capacitor

A low ESR ceramic capacitor (C_{IN}) is needed between the VIN pin and GND pin. This capacitor prevents large voltage transients from appearing at the input. Use a 2.2 μF-10 μF value with X5R or X7R dielectric. Depending on construction, a ceramic capacitor's value can decrease up to 50% of its nominal value when rated voltage is applied. Consult with the capacitor manufacturer's data sheet for information on capacitor derating over voltage and temperature.

Inductor Selection

The most critical parameters for the inductor are the inductance, peak current, and the DC resistance. The inductance is related to the peak-to-peak inductor ripple current, the input and the output voltages.

$$L = \frac{(VIN - VO) * \Delta I}{VIN * I_{RIPPLE} * f}$$

A higher value of ripple current reduces inductance, but increases the conductance loss, core loss, and current stress for the inductor and switch devices. It also requires a bigger output capacitor for the same output voltage ripple requirement. A reasonable value is setting the ripple current to be 30% of the DC output current. Since the ripple current increases with the input voltage, the maximum input voltage is always used to determine the inductance. The DC resistance of the inductor is a key parameter for the efficiency. Lower DC resistance is available with a bigger winding area. A good tradeoff between the efficiency and the core size is letting the inductor copper loss equal 2% of the output power. A good starting point for most applications is a 4.7μH to 15μH with 1A or greater current rating for the ME3116. Using such a rating will enable the ME3116 to current limit without saturating the inductor. This is preferable to the ME3116 going into thermal shutdown mode and the possibility of damaging the inductor if the output is shorted to ground or other long term overload.

Output Capacitor

The selection of Co is driven by the maximum allowable output voltage ripple. The output ripple in the constant

frequency, PWM mode is approximated by:
$$V_{\text{RIPPLE}} = I_{\text{RIPPLE}} * \left(\text{ESR} + \frac{1}{8 * f_{\text{SW}} * C_{\text{O}}} \right)$$

The ESR term usually plays the dominant role in determining the voltage ripple. Low ESR ceramic capacitors are recommended. Capacitors in the range of 22μF-100μF are a good starting point with an ESR of 0.1Ω or less.

Bootstrap Capacitor

A 0.15μF ceramic capacitor or larger is recommended for the bootstrap capacitor (Cboot). For applications where the input voltage is less than twice the output voltage a larger capacitor is recommended, generally 0.15μF to 1μF to ensure plenty of gate drive for the internal switches and a consistently low R_{DS(on)}.

Soft-Start

The built-in soft start, controlled by the clock signal frequency, in order to prevent the current overshoot when opening.

Shutdown Operation

The EN pin of the ME3116 is designed so that it may be controlled using 1.5V or higher logic signals. If the shutdown function is not to be used the EN pin may be tied to VIN with a resistor (A 1MΩ or larger resistor is recommended between the input voltage and the EN pin to protect the device.) . The maximum voltage to the EN pin should not exceed 5V.

Schottky Diode

The breakdown voltage rating of the diode (D1) is preferred to be 25% higher than the maximum input voltage. The

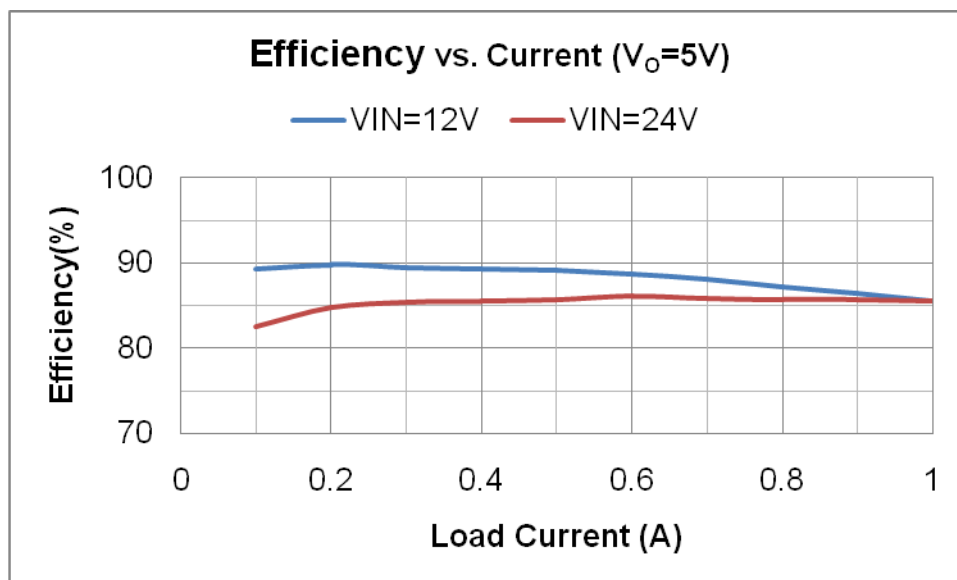
circuit rent rating for the diode should be equal to the maximum output current for best reliability in most applications. In cases where the input voltage is much greater than the output voltage the average diode current is lower. In this case it is possible to use a diode with a lower average current rating, approximately $(1-D)I_o$, however the peak current rating should be higher than the maximum load current 0.5A to 1A rated diode is a good starting point.

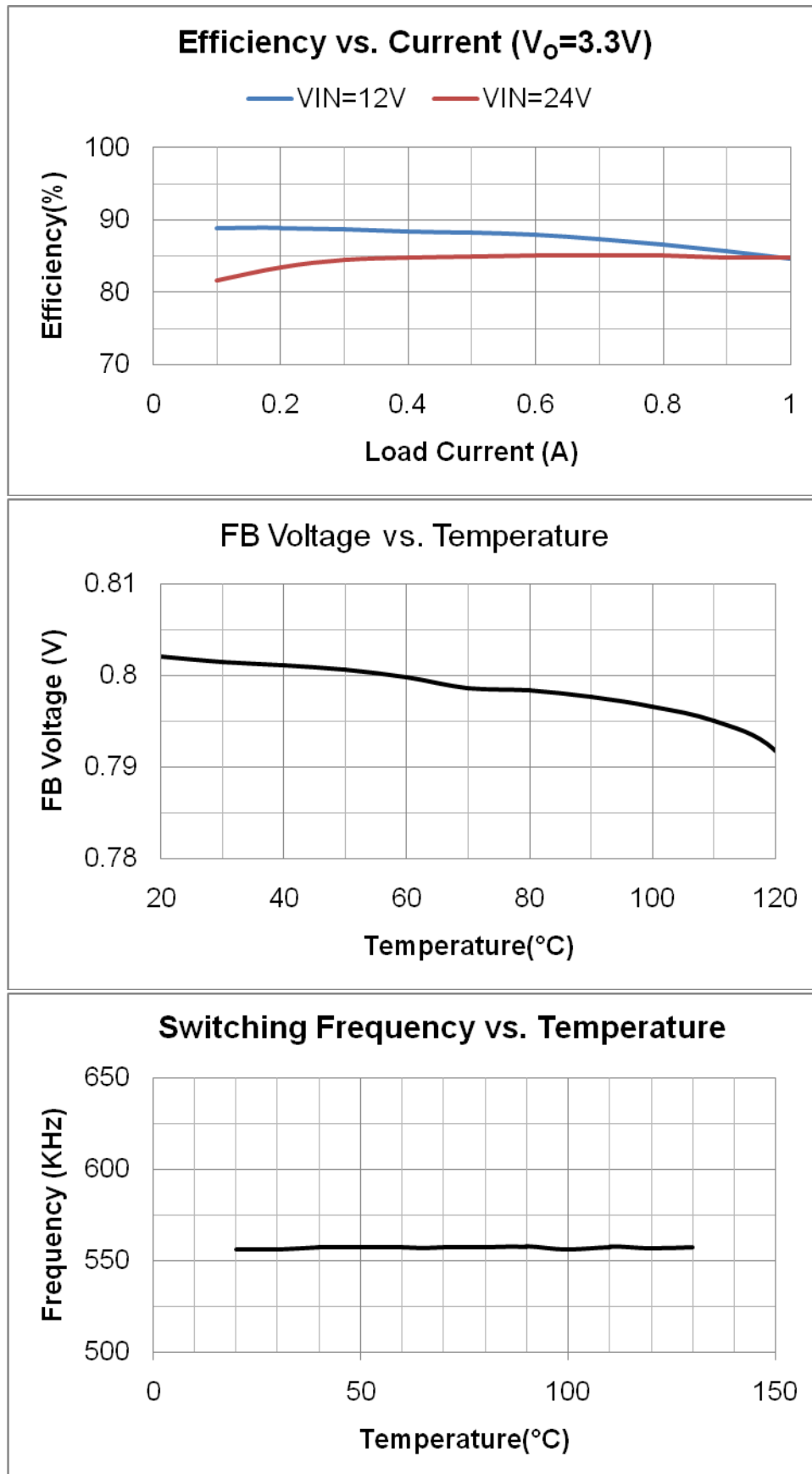
Layout Considerations

To reduce problems with conducted noise pick up, the ground side of the feedback network should be connected directly to the GND pin with its own connection. The feedback network, resistors R1 and R2, should be kept close to the FB pin, and away from the inductor to minimize coupling noise into the feedback pin. The input bypass capacitor C_{IN} must be placed close to the VIN pin. This will reduce copper trace resistance which effects input voltage ripple of the IC. The inductor L should be placed close to the SW pin to reduce magnetic and electrostatic noise. The output capacitor, C_o should be placed close to the junction of L and the diode D1. The L, D1, and C_o trace should be as short as possible to reduce conducted and radiated noise and increase overall efficiency. The ground connection for the diode, C_{IN} , and C_o should be as small as possible and tied to the system ground plane in only one spot (preferably at the C_o ground point) to minimize conducted noise in the system ground plane.

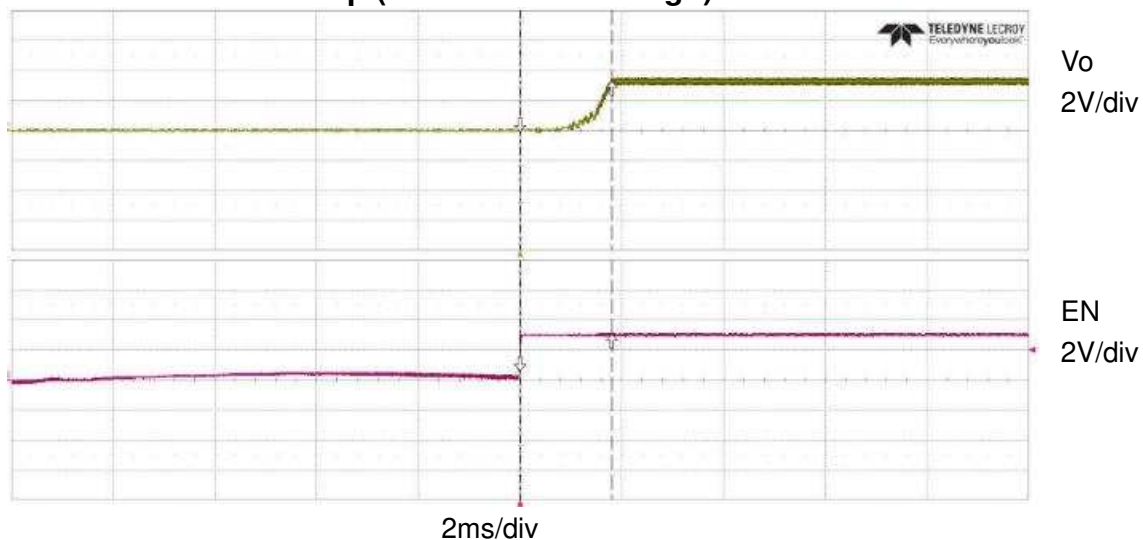
Typical Performance Characteristics

T =25°C, unless otherwise noted.

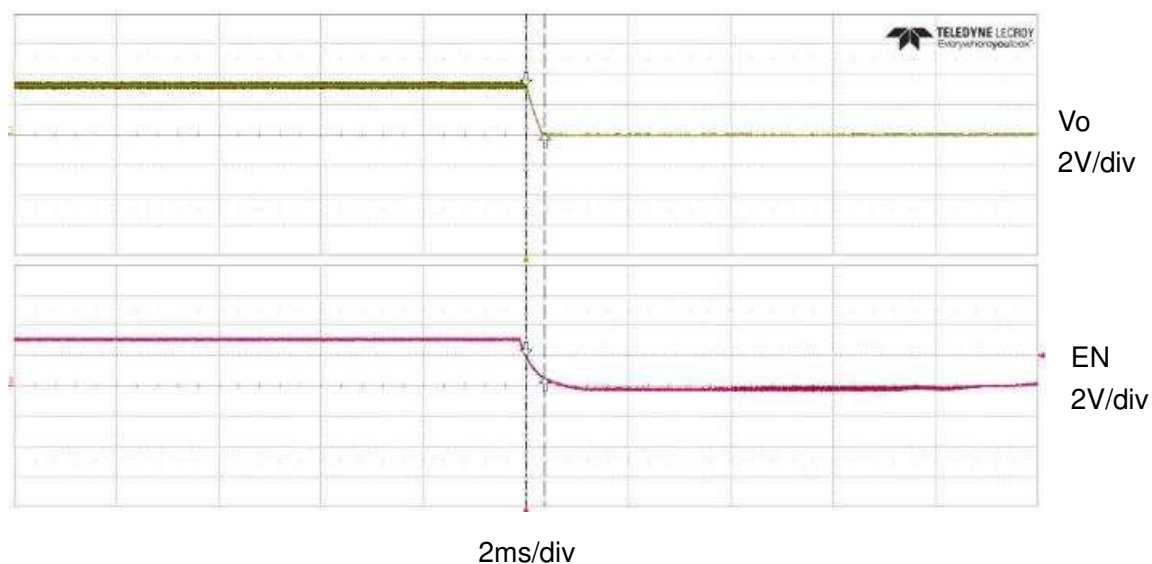




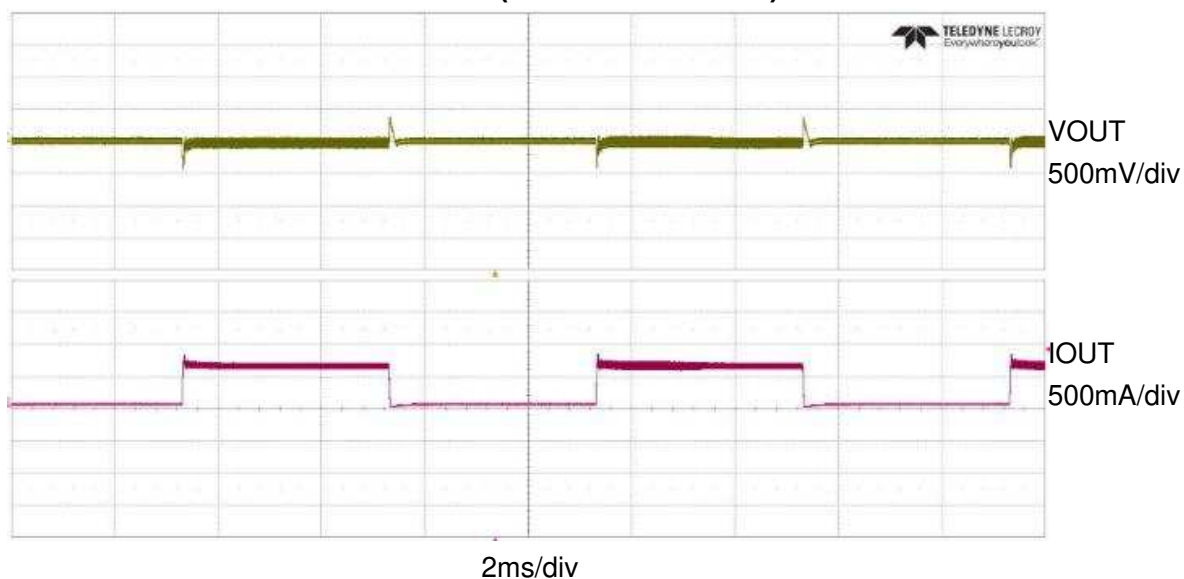
Start up (EN from Low to High)



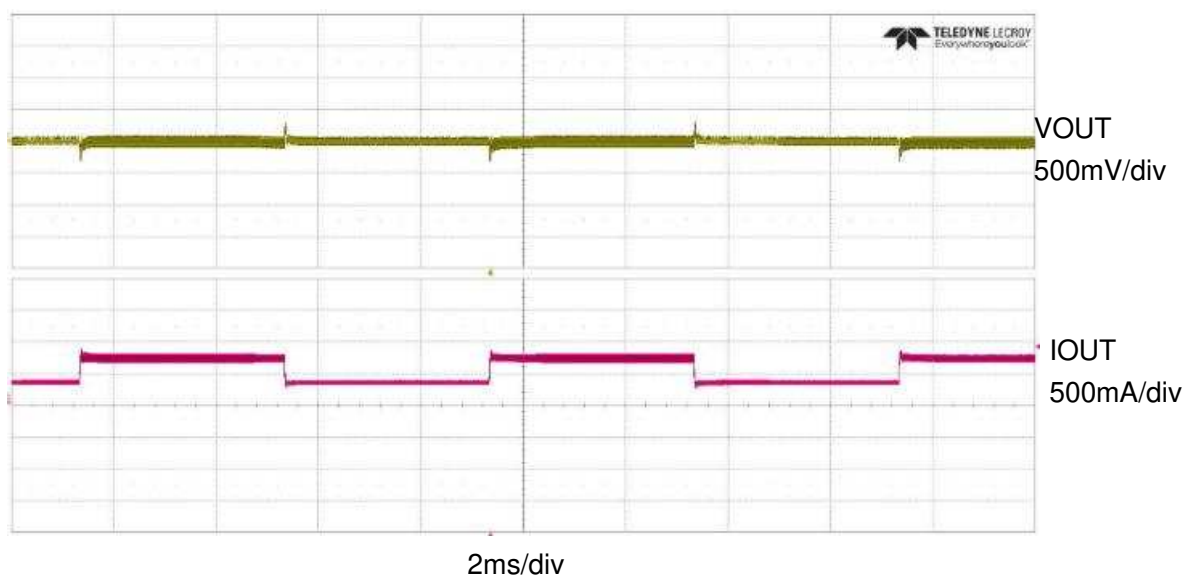
Start up (EN from High to Low)



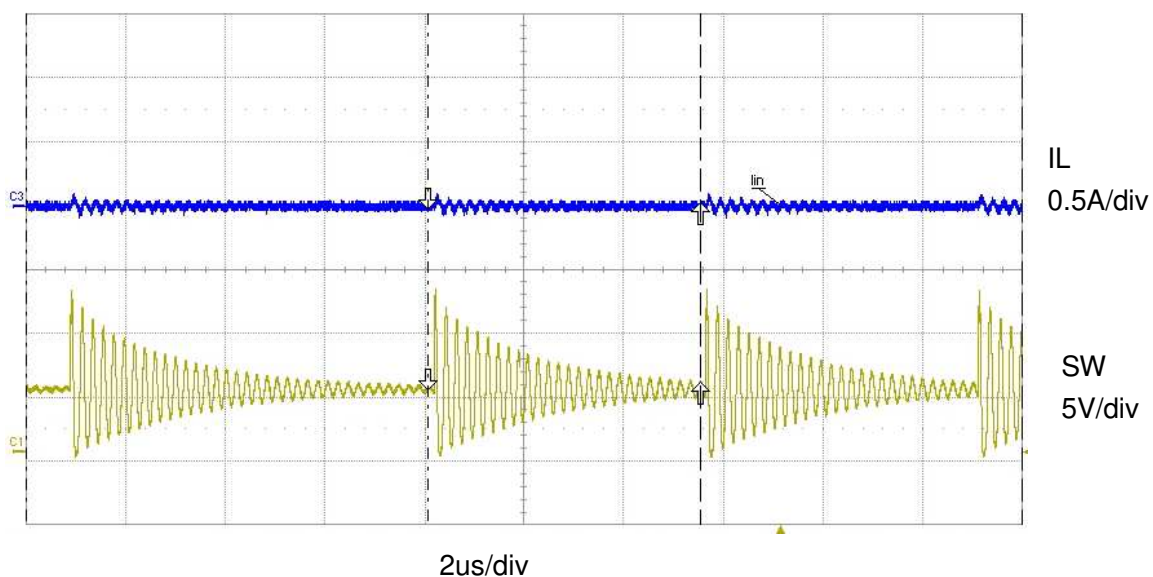
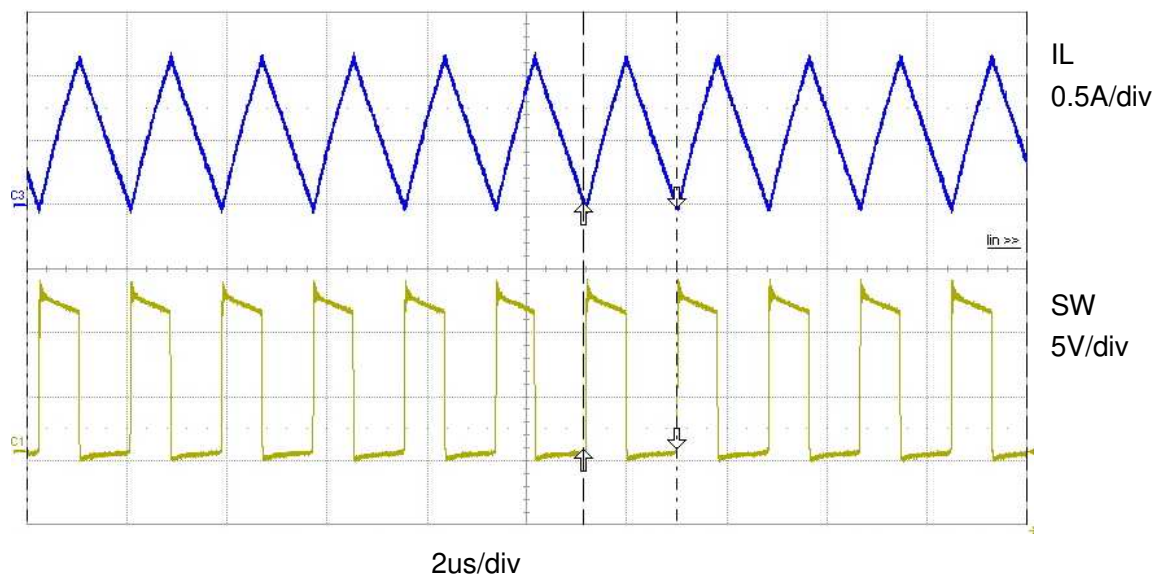
Load Transient (Load 10% to 90%)



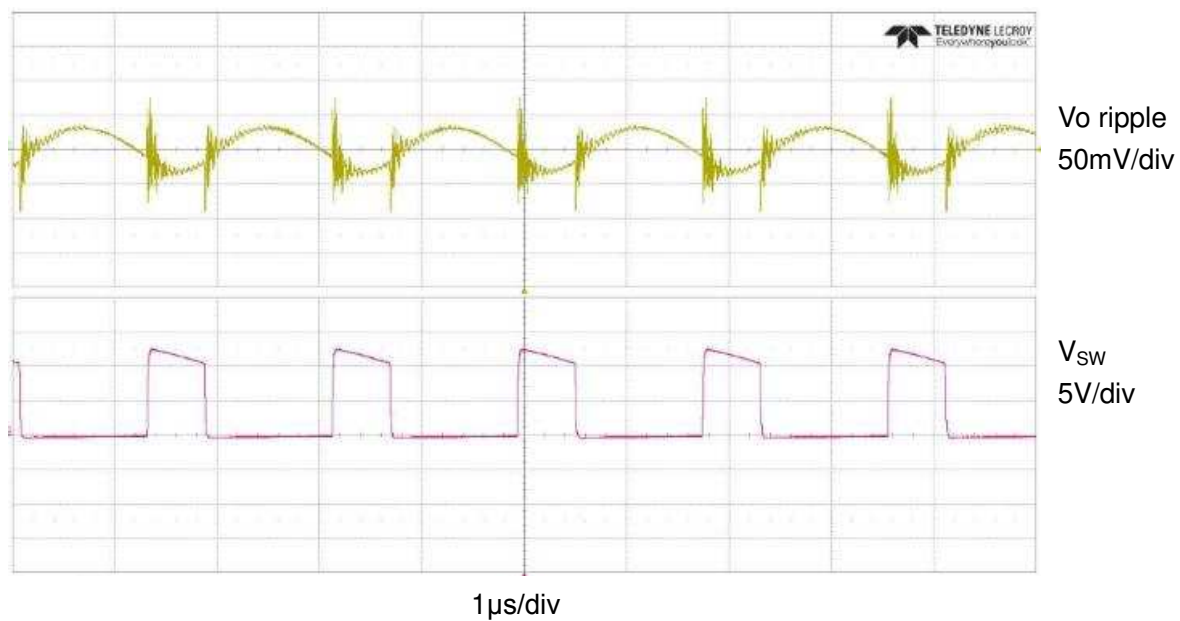
Load Transient (Load 50% to 100%)



PWM and PFM switching

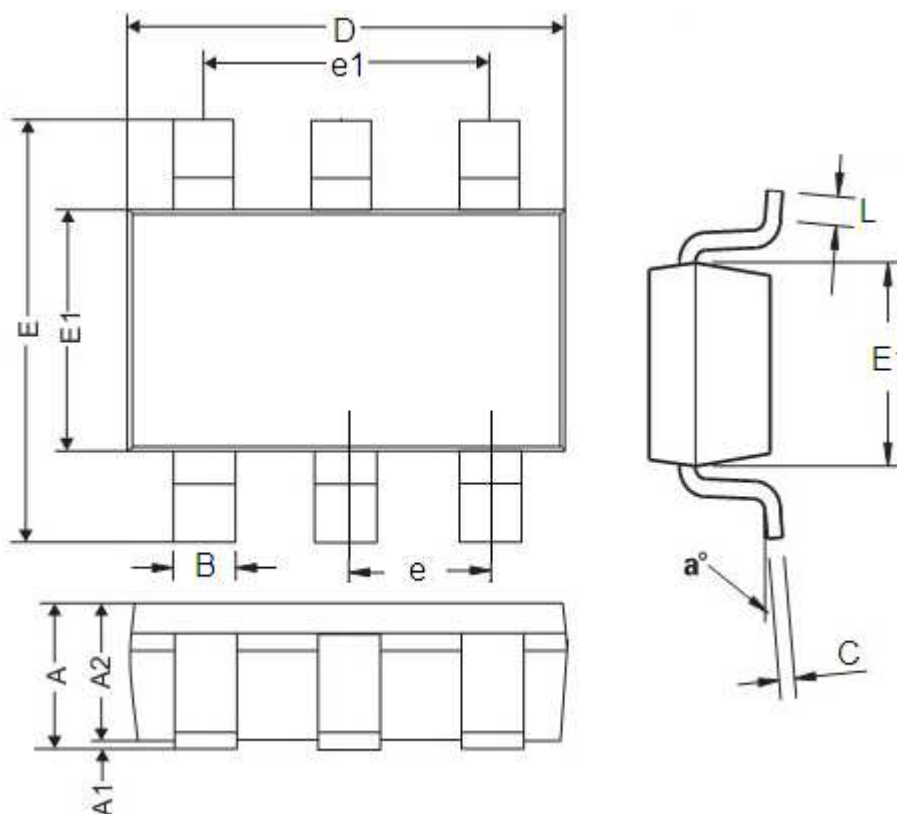


Switching Node and Output ($I_{OUT}=600mA$)



Package Information

Package type:SOT23-6 Unit:mm(inch)



DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	0.9	1.45	0.0354	0.0570
A1	0	0.15	0	0.0059
A2	0.9	1.3	0.0354	0.0511
B	0.2	0.5	0.0078	0.0196
C	0.09	0.26	0.0035	0.0102
D	2.7	3.10	0.1062	0.1220
E	2.2	3.2	0.0866	0.1181
E1	1.30	1.80	0.0511	0.0708
e	0.95REF		0.0374REF	
e1	1.90REF		0.0748REF	
L	0.10	0.60	0.0039	0.0236
a°	0°	30°	0°	30°

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